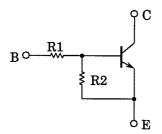
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# RN1107,RN1108,RN1109

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2107~2109

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN1107	10	47
RN1108	22	47
RN1109	47	22

# 1. BASE 2. EMITTER SSM 3. COLLECTOR JEDEC — EIAJ — TOSHIBA 2-2H1A

Weight: 2.4mg

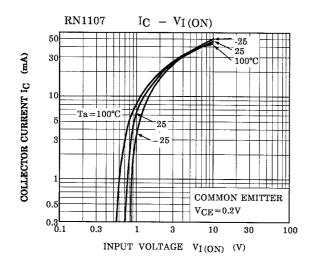
### Maximum Ratings (Ta = 25°C)

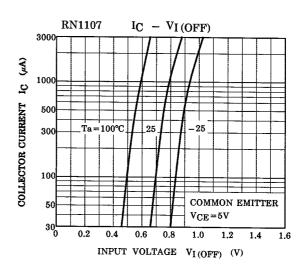
Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN1107~1109	V <sub>CBO</sub> 50		V	
Collector-emitter voltage	RN1107~1109	V <sub>CEO</sub>	50	V	
	RN1107		6		
Emitter-base voltage	RN1108	$V_{EBO}$	7	V	
	RN1109		15		
Collector current	RN1107~1109	I <sub>c</sub>	100	mA	
Collector power dissipation	RN1107~1109	P <sub>c</sub>	100	mW	
Junction temperature	RN1107~1109	Tj	150	°C	
Storage temperature range	RN1107~1109	T <sub>stg</sub>	-55~150	°C	

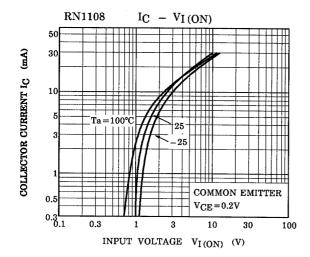
## Electrical Characteristics (Ta = 25°C)

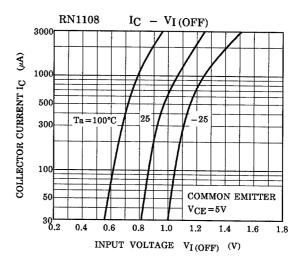
Characteris	etic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1107~1109	I <sub>CBO</sub>	_	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
		I <sub>CEO</sub>	_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	nA
	RN1107		_	V <sub>EB</sub> = 6V, I <sub>C</sub> = 0	0.081	_	0.15	
Emitter cut-off current	RN1108	$I_{EBO}$	_	V <sub>EB</sub> = 7V, I <sub>C</sub> = 0	0.078	_	0.145	mA
	RN1109		_	V <sub>EB</sub> = 15V, I <sub>C</sub> = 0	0.167	_	0.311	1
	RN1107		_		80	_	_	
DC current gain	RN1108	$h_{FE}$	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	80	_	_	_
	RN1109		_		70	_	_	
Collector-emitter saturation voltage	RN1107~1109	V <sub>CE</sub> (sat)	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
	RN1107		_		0.7	_	1.8	
Input voltage (ON)	RN1108	V <sub>I (ON)</sub>	_	V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.0	_	2.6	V
	RN1109		_		2.2	_	5.8	
	RN1107		_		0.5	_	1.0	
Input voltage (OFF)	RN1108	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	0.6	_	1.16	V
	RN1109		_		1.5	_	2.6	
Translation frequency	RN1107~1109	f <sub>T</sub>	_	V <sub>CE</sub> =10V, I <sub>C</sub> = 5mA	_	250	-	MHz
Collector output capacitance	RN1107~1109	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
	RN1107		_		7	10	13	
Input Resistor	RN1108	R1	_	_	15.4	22	28.6	kΩ
	RN1109		_		32.9	47	61.1	
	RN1107		_		0.191	0.213	0.232	
Resistor Ratio	RN1108	R1/R2	_	_	0.421	0.468	0.515	_
	RN1109		_		1.92	2.14	2.35	

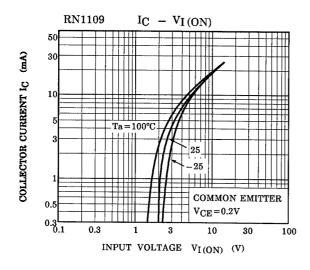
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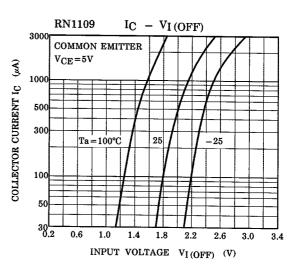


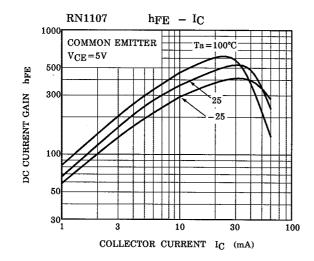


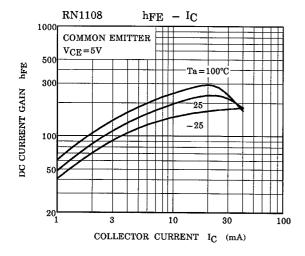


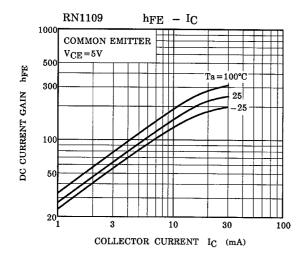












Type Name	Marking
RN1107	Type Name  X H
RN1108	Type Name
RN1109	Type Name  X J

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000707EAA

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